

# Vishay General Semiconductor

## **Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.58 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 



| PRIMARY CHARACTERISTICS                  |                |  |  |  |
|--|----------------|--|--|--|
| Package                                  | TO-220AB       |  |  |  |
| I <sub>F(AV)</sub>                       | 2 x 5.0 A      |  |  |  |
| $V_{RRM}$                                | 200 V          |  |  |  |
| I <sub>FSM</sub>                         | 80 A           |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 5.0 A | 0.65 V         |  |  |  |
| T <sub>J</sub> max.                      | 150 °C         |  |  |  |
| Diode variations                         | Common cathode |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

RoHS COMPLIANT HALOGEN

- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                |                  |                                   |             |      |
|--|------------------|-----------------------------------|-------------|------|
| PARAMETER  |                  | SYMBOL                            | VT10200C    | UNIT |
| Maximum repetitive peak reverse voltage  |                  | $V_{RRM}$                         | 200         | V    |
| Maximum average forward rectified current (fig. 1)                             | per device       | I <sub>F(AV)</sub>                | 10.0        | - A  |
|  | per diode        |                                   | 5.0         |      |
| Peak forward surge current 8.3 ms single half sine-way on rated load per diode | I <sub>FSM</sub> | 80                                | А           |      |
| Voltage rate of change (rated V <sub>R</sub> )                                 |                  | dV/dt                             | 10 000      | V/µs |
| Operating junction and storage temperature range                               |                  | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150 | °C   |

| PARAMETER                               | TEST CONDITIONS         |   | SYMBOL                        | TYP.          | MAX. | UNIT |
|---|-------------------------|---|-------------------------------|---------------|------|------|
| Breakdown voltage                       | I <sub>R</sub> = 1.0 mA | T <sub>A</sub> = 25 °C                                | $V_{BR}$                      | 200 (minimum) | -    | V    |
| Instantaneous forward voltage per diode | I <sub>F</sub> = 2.5 A  | - T <sub>A</sub> = 25 °C<br>- T <sub>A</sub> = 125 °C | V <sub>F</sub> <sup>(1)</sup> | 0.81          | -    | V    |
|   | I <sub>F</sub> = 5.0 A  |   |                               | 1.10          | 1.60 |      |
|   | I <sub>F</sub> = 2.5 A  |   |                               | 0.58          | -    |      |
|   | I <sub>F</sub> = 5.0 A  |   |                               | 0.65          | 0.73 |      |
| Reverse current per diode               | V <sub>R</sub> = 180 V  | T <sub>A</sub> = 25 °C                                | I <sub>R</sub> <sup>(2)</sup> | 1.7           | -    | μΑ   |
|   |                         | T <sub>A</sub> = 125 °C                               |                               | 1.8           | -    | mA   |
|   | $V_D = 200 V -$         | T <sub>A</sub> = 25 °C                                |                               | -             | 150  | μA   |
|   |                         | T <sub>A</sub> = 125 °C                               |                               | 2.5           | 10   | mA   |

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |               |          |      |
|---|------------|---------------|----------|------|
| PARAMETER   |            | SYMBOL        | VT10200C | UNIT |
| Typical thermal resistance  | per diode  | $R_{	hetaJC}$ | 3.5      | °C/W |
|   | per device |               | 2.5      |      |

| ORDERING INFORMATION (Example) |                |                 |              |               |               |  |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE                        | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |
| TO-220AB                       | VT10200C-M3/4W | 1.88            | 4W           | 50/tube       | Tube          |  |

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

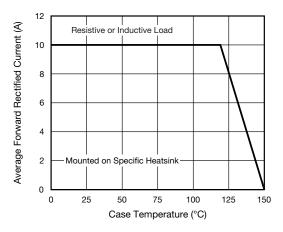


Fig. 1 - Maximum Forward Current Derating Curve

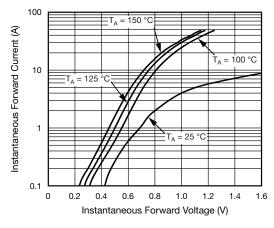


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

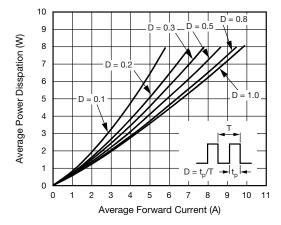


Fig. 2 - Forward Power Loss Characteristics Per Device

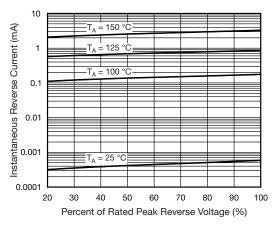


Fig. 4 - Typical Reverse Characteristics Per Diode



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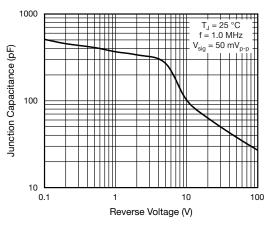


Fig. 5 - Typical Junction Capacitance Per Diode

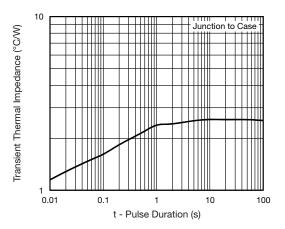
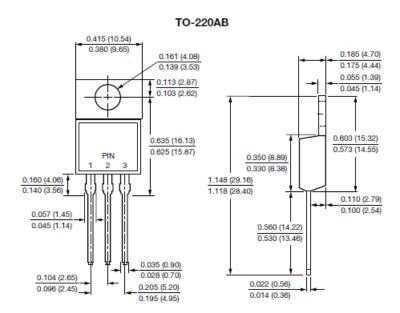


Fig. 6 - Typical Transient Thermal Impedance Per Device

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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